EPISTAR

ES-SA81DN30

AlGaAs DN-series LED Chip

> Mechanical Specification:

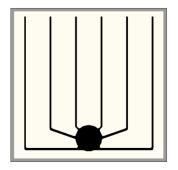
(1) Dimension

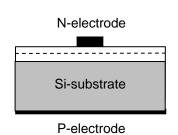
- Chip size: 30 mil x 30 mil (772±25 μm x 772±25 μm)

- Thickness: 6.7 mil (170±25 μ m) - N bonding pad: 5.1 mil (130±10 μ m)

(2) Metallization

Topside N electrode : Au alloyBackside P electrode: Au alloy





Features:

- · High radiant flux
- · Thin film structure
- · Vertical electrode
- · High driving current

Applications:

IRIS Recognition

> Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward Voltage	Vf1		If = 10μA	1.4	-	-	V
	Vf2		If = 500mA	-	3.25	3.5	V
Reverse Current	Ir		Vr = 10V	-	-	5.0	μΑ
Peak Wavelength ⁽¹⁾	λр		If = 500mA	795	810	825	nm
Spectra Half-width	Δλ		If = 500mA	-	32	-	nm
Radiant flux ⁽²⁾⁽³⁾	Ро	C19	If = 500mA	420	-	-	mW
		C20		470	-	-	

Note:

⁽¹⁾ Basically, the wavelength span is 30nm; however, customers' special requirements are also welcome.

⁽²⁾ Customers' special requirements are also welcome.

⁽³⁾ Radiant flux is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 500	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 10	V
Junction Temperature	Tj	-	≤ 115	°C
		Chip	-40 ~ +85	°C
Storage Temperature	Tstg	Chip-on-tape/storage	5~35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MCPCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 – Relative Radiant Flux vs. Forward Current

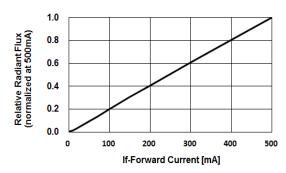


Fig.3 – Relative Radiant Flux (@500mA) vs. Ambient Temperature

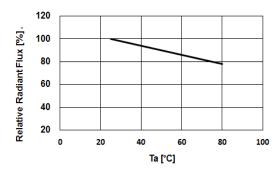


Fig.5 – Peak Wavelength (@500mA) vs. Ambient Temperature

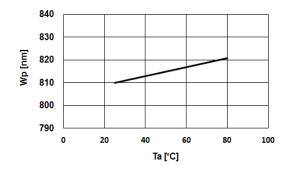


Fig.2 – Forward Current vs. Forward Voltage

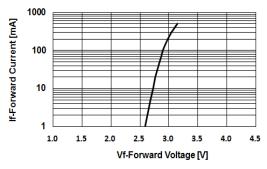


Fig.4 – Forward Voltage (@500mA) vs. Ambient Temperature

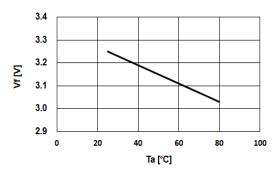


Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 115°C)

